NSN 5961-01-452-8503

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Inclosure Material:

Metal

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

